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## MAX338/MAX339

## 8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

### General Description

The MAX338/MAX339 are monolithic, CMOS analog multiplexers (muxes). The 8-channel MAX338 is designed to connect one of eight inputs to a common output by control of a 3-bit binary address. The dual, 4-channel MAX339 is designed to connect one of four inputs to a common output by control of a 2-bit binary address. Both devices can be used as either a mux or a demux. On-resistance is  $400\Omega$  max, and the devices conduct current equally well in both directions.

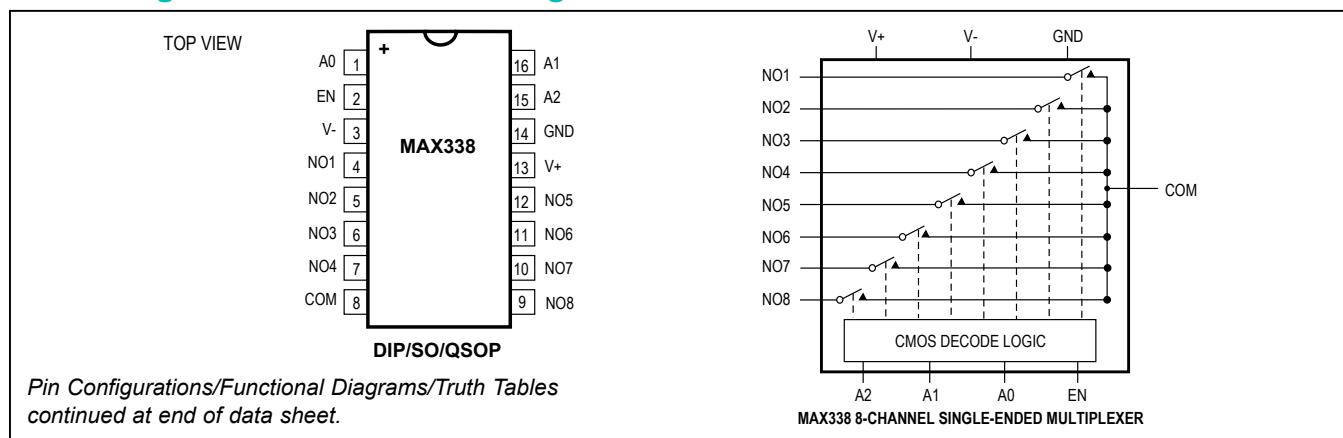
These muxes feature extremely low off leakages (less than  $20\text{pA}$  at  $+25^\circ\text{C}$ ), and extremely low on-channel leakages (less than  $50\text{pA}$  at  $+25^\circ\text{C}$ ). The new design offers guaranteed low charge injection ( $1.5\text{pC}$  typ) and electrostatic discharge (ESD) protection greater than  $2000\text{V}$ , per method 3015.7. These improved muxes are pin-compatible upgrades for the industry-standard DG508A and DG509A. For similar Maxim devices with lower leakage and charge injection but higher on-resistance, see the MAX328 and MAX329.

The MAX338/MAX339 operate from a single  $+4.5\text{V}$  to  $+30\text{V}$  supply or from dual supplies of  $\pm 4.5\text{V}$  to  $\pm 20\text{V}$ . All control inputs (whether address or enable) are TTL compatible ( $+0.8\text{V}$  to  $+2.4\text{V}$ ) over the full specified temperature range and over the  $\pm 4.5\text{V}$  to  $\pm 18\text{V}$  supply range. These parts are fabricated with Maxim's 44V silicon-gate process.

### Applications

- Data-Acquisition Systems
- Test Equipment
- Military Radios
- Guidance and Control Systems
- Sample-and-Hold Circuits
- Heads-Up Displays
- Communications Systems
- PBX, PABX

### Pin Configurations/Functional Diagrams/Truth Tables



**Absolute Maximum Ratings**

Voltage Referenced to V

V+	-0.3V, 44V
GND	-0.3V, 25V
Digital Inputs, NO, COM (Note 1)	(V- - 2V) to (V+ + 2V) or 30mA (whichever occurs first)
Continuous Current (any terminal)	30mA
Peak Current, NO or COM (pulsed at 1ms, 10% duty cycle max)	100mA
Continuous Power Dissipation ( $T_A = +70^\circ\text{C}$ ) Plastic DIP (derate 10.53mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$ )	842mW
Narrow SO (derate 8.70mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$ )	696mW
16 QSOP (derate 8.3mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$ )	666.7mW

**Note 1:** Signals on NO, COM, EN, A0, A1, or A2 exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Electrical Characteristics—Dual Supplies**

( $V_+ = +15\text{V}$ ,  $V_- = -15\text{V}$ ,  $V_{\text{GND}} = 0\text{V}$ ,  $V_{\text{AH}} = +2.4\text{V}$ ,  $V_{\text{AL}} = +0.8\text{V}$ ,  $T_A = T_{\text{MIN}}$  to  $T_{\text{MAX}}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
<b>SWITCH</b>							
Analog Signal Range	$V_{\text{NO}}, V_{\text{COM}}$	(Note 3)		-15		15	V
On-Resistance	$R_{\text{ON}}$	$I_{\text{NO}} = 0.2\text{mA}$ , $V_{\text{COM}} = \pm 10\text{V}$	$T_A = +25^\circ\text{C}$		220	400	$\Omega$
			$T_A = T_{\text{MIN}}$ to $T_{\text{MAX}}$			500	
On-Resistance Matching Between Channels	$\Delta R_{\text{ON}}$	$I_{\text{NO}} = 0.2\text{mA}$ , $V_{\text{COM}} = \pm 10\text{V}$ (Note 4)	$T_A = +25^\circ\text{C}$		4	10	$\Omega$
			$T_A = T_{\text{MIN}}$ to $T_{\text{MAX}}$			15	
NO-Off Leakage Current (Note 5)	$I_{\text{NO(OFF)}}$	$V_{\text{COM}} = +10\text{V}$ , $V_{\text{NO}} = \pm 10\text{V}$ , $V_{\text{EN}} = 0\text{V}$	$T_A = +25^\circ\text{C}$	-0.02	0.001	0.02	nA
			$T_A = T_{\text{MIN}}$ to $T_{\text{MAX}}$	C, E	-1.25	1.25	
				M	-20	20	
COM-Off Leakage Current (Note 5)	$I_{\text{COM(OFF)}}$	$V_{\text{NO}} = \pm 10\text{V}$ , $V_{\text{COM}} = +10\text{V}$ , $V_{\text{EN}} = 0\text{V}$	MAX338	$T_A = +25^\circ\text{C}$	-0.05	0.005	0.05
				$T_A = T_{\text{MIN}}$ to $T_{\text{MAX}}$	C, E	-3.25	3.25
					M	-40	40
		$V_{\text{COM}} = +10\text{V}$ , $V_{\text{NO}} = \pm 10\text{V}$ , $V_{\text{EN}} = 0\text{V}$	MAX339	$T_A = +25^\circ\text{C}$	-0.05	0.005	0.05
			MAX339	$T_A = T_{\text{MIN}}$ to $T_{\text{MAX}}$	C, E	-1.65	1.65
					M	-20	20
COM-On Leakage Current (Note 5)	$I_{\text{COM(ON)}}$	$V_{\text{COM}} = \pm 10\text{V}$ , $V_{\text{NO}} = \pm 10\text{V}$ , Sequence each switch on	MAX338	$T_A = +25^\circ\text{C}$	-0.05	0.006	0.05
				$T_A = T_{\text{MIN}}$ to $T_{\text{MAX}}$	C, E	-3.25	3.25
					M	-40	40
		$T_A = +25^\circ\text{C}$	MAX339	$T_A = +25^\circ\text{C}$	-0.05	0.008	0.05
			MAX339	$T_A = T_{\text{MIN}}$ to $T_{\text{MAX}}$	C, E	-1.65	1.65
					M	-20	20

**Electrical Characteristics—Dual Supplies (continued)**(V<sub>+</sub> = +15V, V<sub>-</sub> = -15V, V<sub>GND</sub> = 0V, V<sub>AH</sub> = +2.4V, V<sub>AL</sub> = +0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS		
(Note 2)									
<b>INPUT</b>									
Input Current with Input Voltage High	I <sub>AH</sub>	V <sub>A</sub> = 2.4V or 15V		-1.0	0.001	1.0	µA		
Input Current with Input Voltage Low	I <sub>AL</sub>	V <sub>EN</sub> = 0V or 2.4V, V <sub>A</sub> = 0V		-1.0		1.0	µA		
<b>SUPPLY</b>									
Power-Supply Range				±4.5	±20		V		
Positive Supply Current	I <sub>+</sub>	V <sub>EN</sub> = V <sub>A</sub> = 0V	T <sub>A</sub> = +25°C	50	100		µA		
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		150				
	I <sub>+</sub>	V <sub>EN</sub> = 2.4V, V <sub>A(ALL)</sub> = 2.4V	T <sub>A</sub> = +25°C	290	500		µA		
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		600				
Negative Supply Current	I <sub>-</sub>	V <sub>EN</sub> = 0V or 2.4V, V <sub>A(ALL)</sub> = 0V, 2.4V or 5V	T <sub>A</sub> = +25°C	-1	1		µA		
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>	-10	10				
<b>DYNAMIC</b>									
Transition Time	t <sub>TRANS</sub>	Figure 2	T <sub>A</sub> = +25°C/ T <sub>A</sub> = -55°C	200	500		ns		
			T <sub>A</sub> = +125°C		650		ns		
Break-Before-Make Interval	t <sub>OPEN</sub>	Figure 4	T <sub>A</sub> = +25°C	10	140		ns		
Enable Turn-On Time	t <sub>ON(EN)</sub>	Figure 3	T <sub>A</sub> = +25°C	160	500		ns		
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		750				
Enable Turn-Off Time	t <sub>OFF(EN)</sub>	Figure 3	T <sub>A</sub> = +25°C	100	500		ns		
			T <sub>A</sub> = T <sub>MIN</sub> to T <sub>MAX</sub>		750				
Charge Injection (Note 3)	Q	C <sub>L</sub> = 100pF, V <sub>NO</sub> = 0V, R <sub>S</sub> = 0Ω, Figure 6	T <sub>A</sub> = +25°C	1.5	5		pC		
Off Isolation (Note 6)	V <sub>ISO</sub>	V <sub>EN</sub> = 0V, R <sub>L</sub> = 1kΩ, f = 100kHz	T <sub>A</sub> = +25°C	-75			dB		
Crosstalk Between Channels	V <sub>CT</sub>	V <sub>EN</sub> = 2.4V, f = 100kHz, V <sub>GEN</sub> = 1V <sub>P-P</sub> , R <sub>L</sub> = 1kΩ, Figure 7	T <sub>A</sub> = +25°C	-92			dB		
Logic Input Capacitance	C <sub>IN</sub>	f = 1MHz	T <sub>A</sub> = +25°C	2			pF		
NO-Off Capacitance	C <sub>NO(OFF)</sub>	f = 1MHz, V <sub>EN</sub> = V <sub>NO</sub> = 0V, Figure 8	T <sub>A</sub> = +25°C	3			pF		
COM-Off Capacitance	C <sub>COM(OFF)</sub>	f = 1MHz, V <sub>EN</sub> = 0.8V, V <sub>COM</sub> = 0V, Figure 8	MAX338	11			pF		
			MAX339	TA = +25°C	6				
COM-On Capacitance	C <sub>COM(ON)</sub>	f = 1MHz, V <sub>EN</sub> = 2.4V, V <sub>COM</sub> = 0V, Figure 8	MAX338	TA = +25°C	16		pF		
			MAX339	TA = +25°C	9				

**Electrical Characteristics—Single Supply**(V<sub>+</sub> = +12V, V<sub>-</sub> = 0V, V<sub>GND</sub> = 0V, V<sub>AH</sub> = +2.4V, V<sub>AL</sub> = +0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
SWITCH							(Note 2)
Analog Signal Range	V <sub>NO</sub> , V <sub>COM</sub>	(Note 3)			0	12	V
On-Resistance	R <sub>ON</sub>	I <sub>NO</sub> = 0.2mA V <sub>COM</sub> = 3V or 10V	T <sub>A</sub> = +25°C	460	650	650	Ω
DYNAMIC							
Transition Time (Note 3)	t <sub>TRANS</sub>	V <sub>NO1</sub> = 8V, V <sub>NO8</sub> = 0V, V <sub>IN</sub> = 2.4V, Figure 1	T <sub>A</sub> = +25°C/ T <sub>A</sub> = -55°C	210	500	500	ns
				800	800	800	ns
Enable Turn-On Time (Note 3)	t <sub>ON(EN)</sub>	V <sub>INH</sub> = 2.4V, V <sub>INL</sub> = 0V, V <sub>NO1</sub> = 5V, Figure 3	T <sub>A</sub> = +25°C	280	500	500	ns
Enable Turn-Off Time (Note 3)	t <sub>OFF(EN)</sub>	V <sub>INH</sub> = 2.4V, V <sub>INL</sub> = 0V, V <sub>NO1</sub> = 5V, Figure 3	T <sub>A</sub> = +25°C	110	500	500	ns
Charge Injection (Note 3)	Q	C <sub>L</sub> = 100pF, V <sub>NO</sub> = 0V, R <sub>S</sub> = 0Ω	T <sub>A</sub> = +25°C	1.8	5	5	ns

**Note 2:** The algebraic convention where the most negative value is a minimum and the most positive value a maximum is used in this data sheet.

**Note 3:** Guaranteed by design.

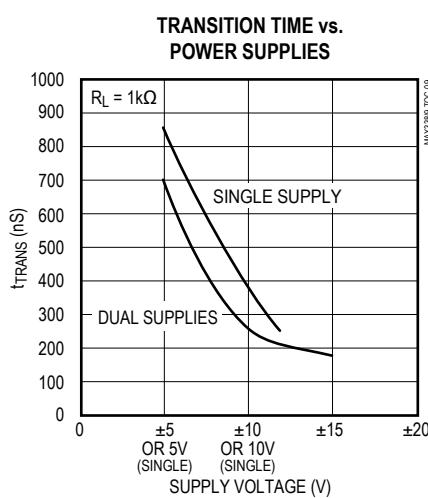
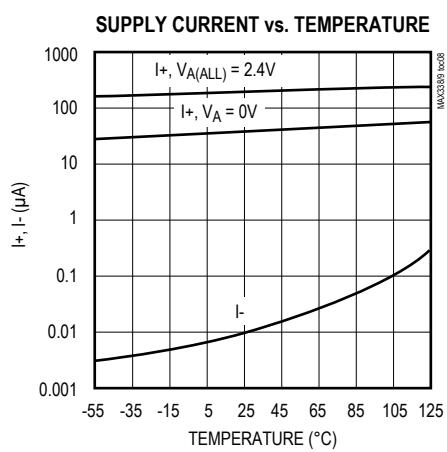
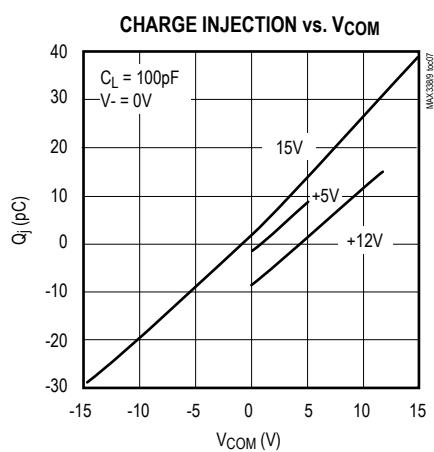
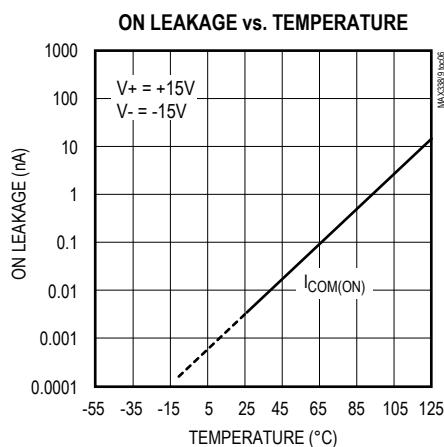
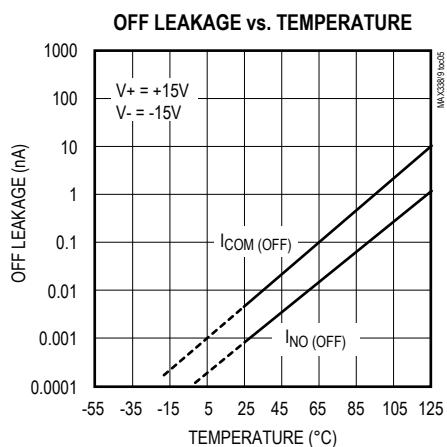
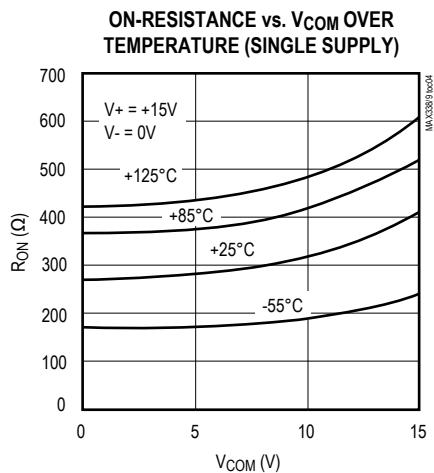
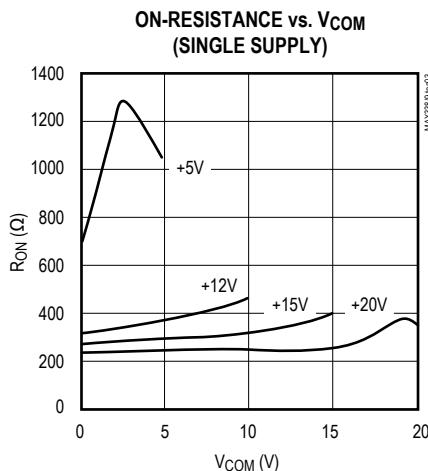
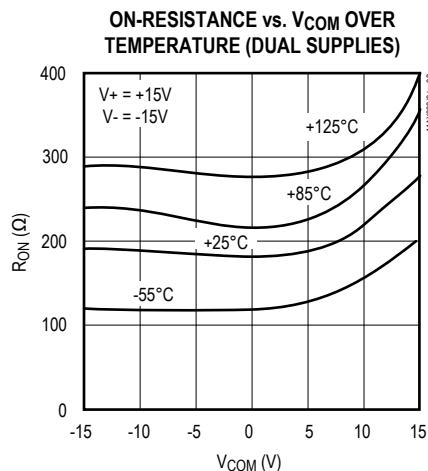
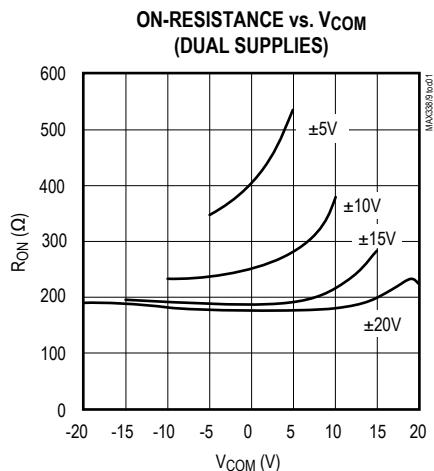
**Note 4:**  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ .

**Note 5:** Leakage parameters are 100% tested at the maximum rated hot temperature and guaranteed by correlation at +25°C.

**Note 6:** Worst-case isolation is on channel 4 because of its proximity to the drain pin. Off isolation =  $20\log V_{COM}/V_{NO}$ , where V<sub>COM</sub> = output and V<sub>NO</sub> = input to off switch.

**Typical Operating Characteristics**

(TA = +25°C, unless otherwise noted.)



## Pin Description

PIN				NAME	FUNCTION
MAX338		MAX339			
DIP/SO/QSOP	TQFN-EP	DIP/SO/QSOP	TQFN-EP		
1, 15, 16,	15, 14, 13	—	—	A0, A2, A1	Address Inputs
—	—	1, 16	15, 14	A0, A1	Address Inputs
2	16	2	16	EN	Enable
3	1	3	1	V-	Negative-Supply Voltage Input
4–7	2–5	—	—	NO1–NO14	Analog Inputs—Bidirectional
—	—	4–7	2–5	NO1A–NO4A	Analog Inputs—Bidirectional
8	6	—	—	COM	Analog Output—Bidirectional
—	—	8, 9	6, 7	COMA, COMB	Analog Outputs—Bidirectional
9–12	7–10	—	—	NO8–NO5	Analog Inputs—Bidirectional
—	—	10–13	8–11	NO4B–NO1B	Analog Inputs—Bidirectional
13	11	14	12	V+	Positive-Supply Voltage Input
14	12	15	13	GND	Ground
—	—	—	—	Exposed Pad	Exposed Pad (TQFN only). Connect EP to V+.

## Applications Information

### Operation with Supply Voltages Other than 15V

Using supply voltages less than  $\pm 15\text{V}$  will reduce the analog signal range. The MAX338/MAX339 switches operate with  $\pm 4.5\text{V}$  to  $\pm 20\text{V}$  bipolar supplies or with a  $+4.5\text{V}$  to  $+30\text{V}$  single supply. Connect V- to GND when operating with a single supply. Both device types can also operate with unbalanced supplies such as  $+24\text{V}$  and  $-5\text{V}$ . The *Typical Operating Characteristics* graphs show typical on-resistance with  $20\text{V}$ ,  $15\text{V}$ ,  $10\text{V}$ , and  $5\text{V}$  supplies. (Switching times increase by a factor of two or more for operation at  $5\text{V}$ .)

### Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs NO and COM. If power-supply sequencing is not possible, add two small signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed 44V.

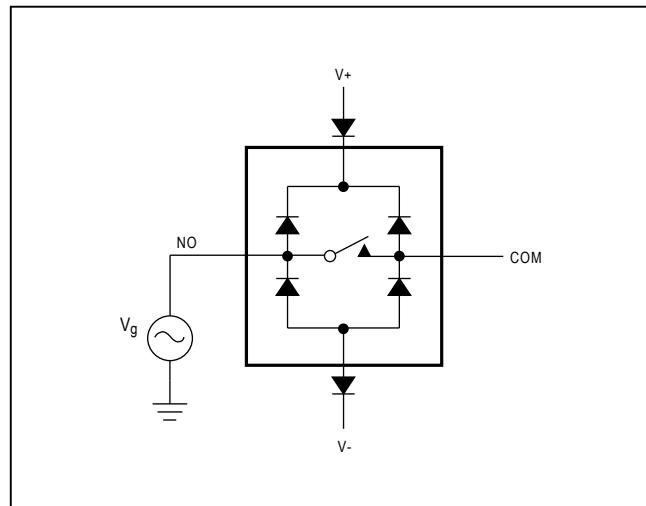


Figure 1. Overvoltage Protection Using External Blocking Diodes

## Test Circuits/Timing Diagrams

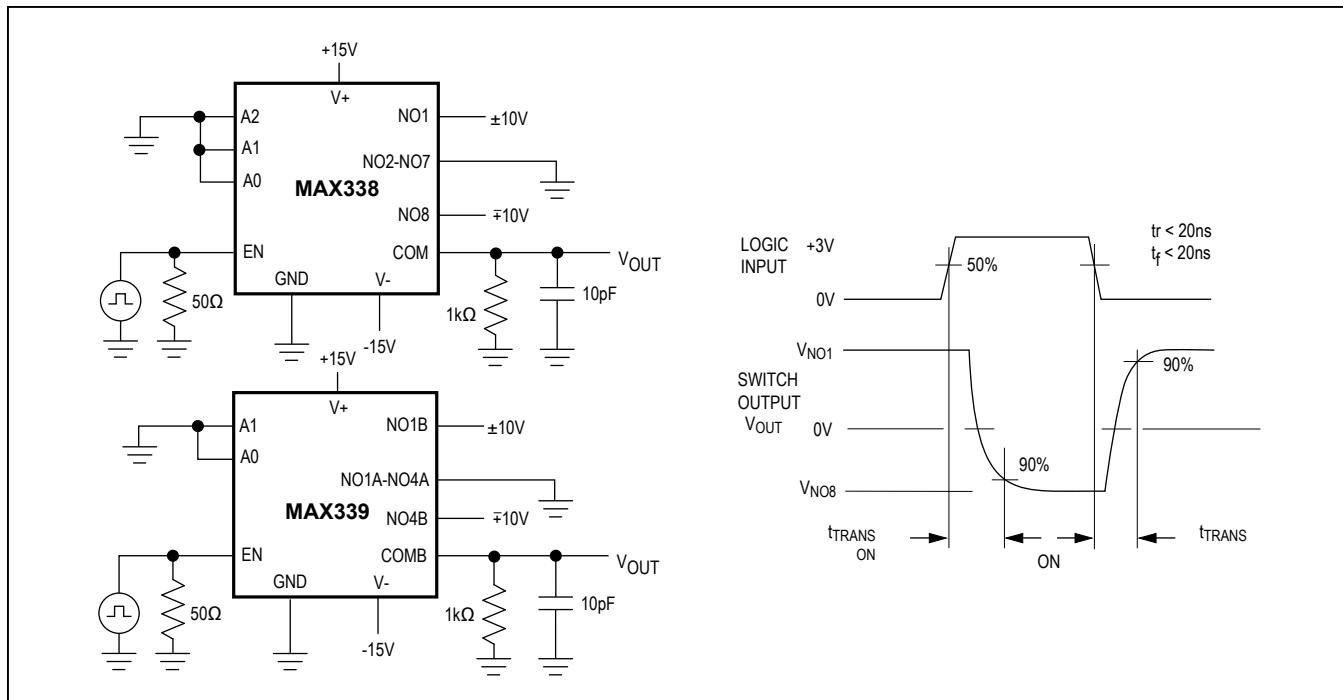


Figure 2. Transition Time

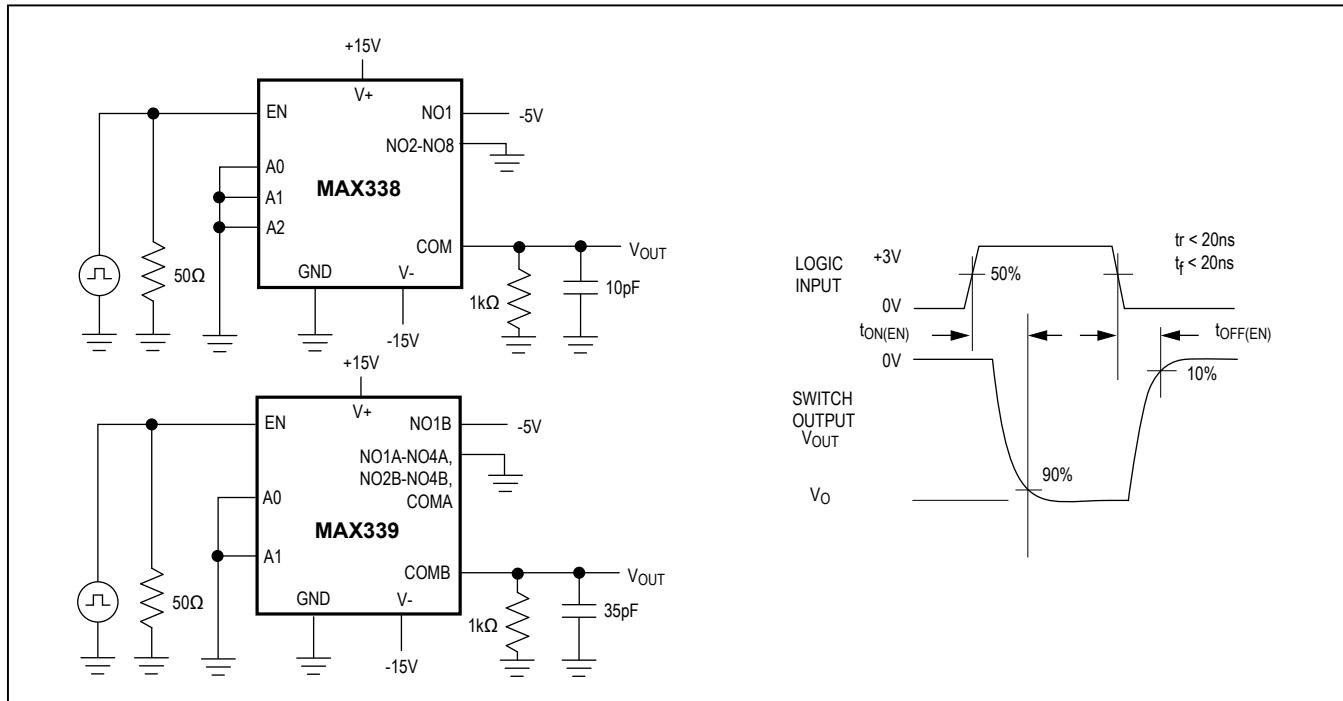


Figure 3. Enable Switching Time

## Test Circuits/Timing Diagrams (continued)

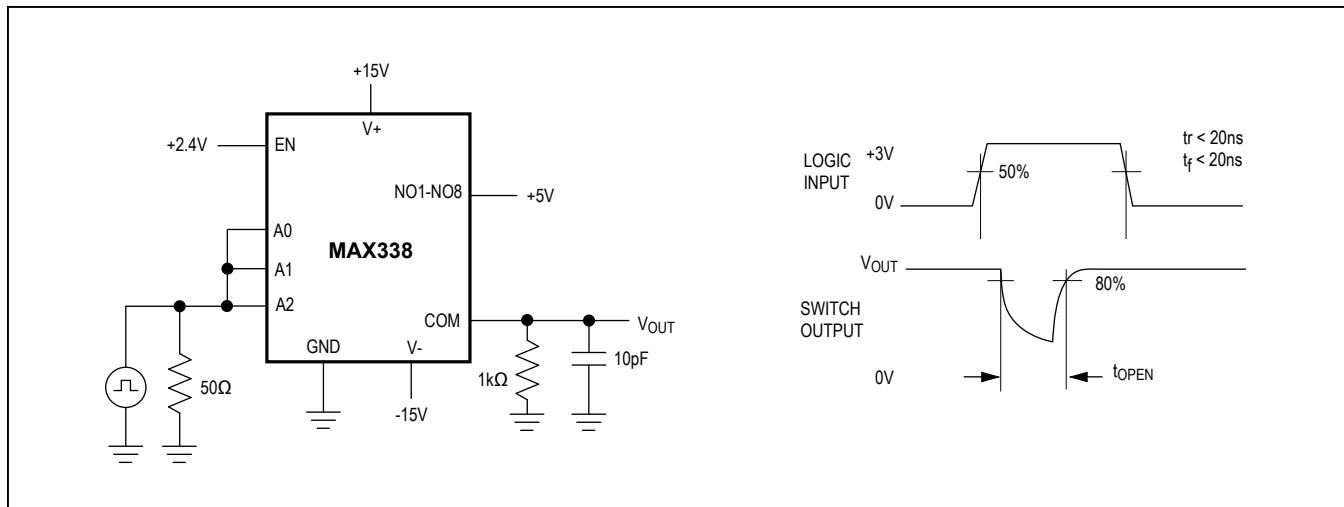


Figure 4. Break-Before-Make Interval

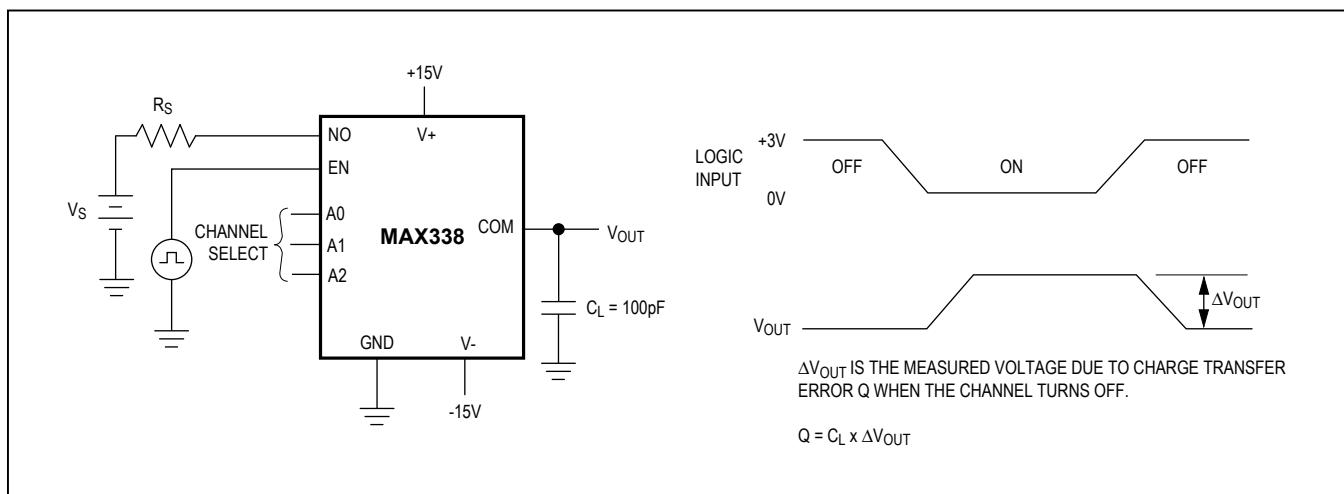


Figure 5. Charge Injection

## MAX338/MAX339

8-Channel/Dual 4-Channel,  
Low-Leakage, CMOS Analog Multiplexers

### Test Circuits/Timing Diagrams (continued)

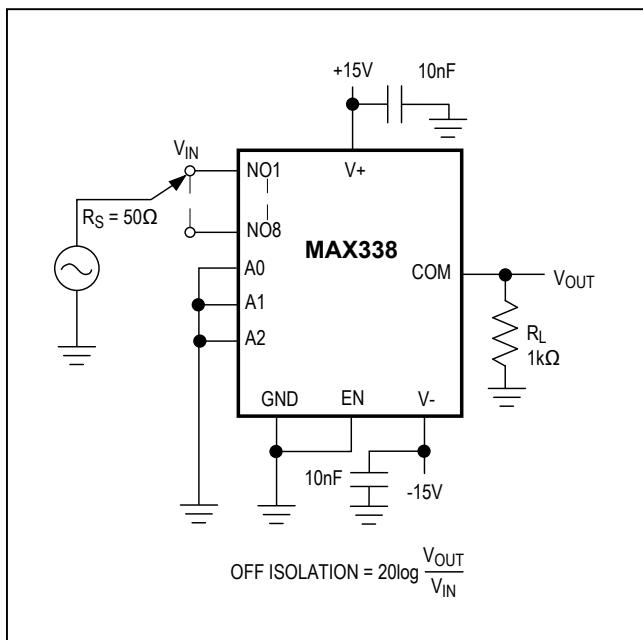


Figure 6. Off-Isolation

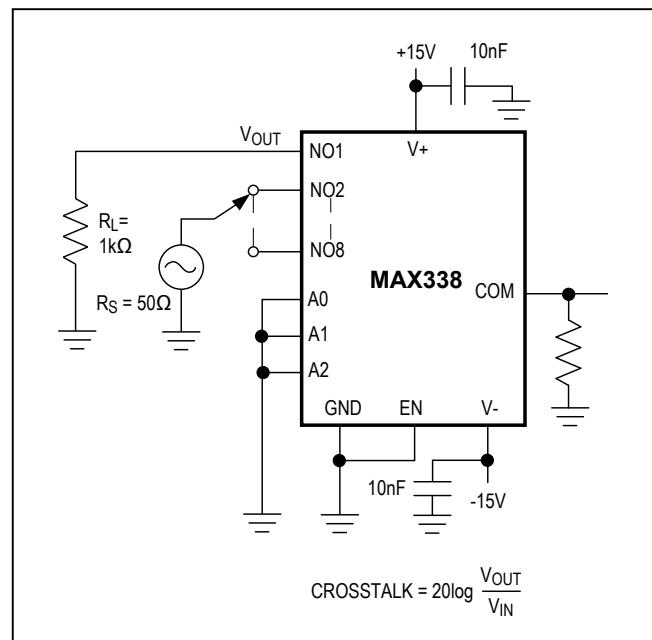


Figure 7. Crosstalk

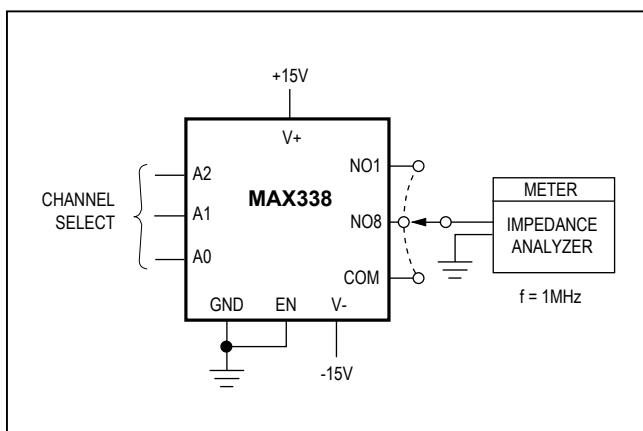
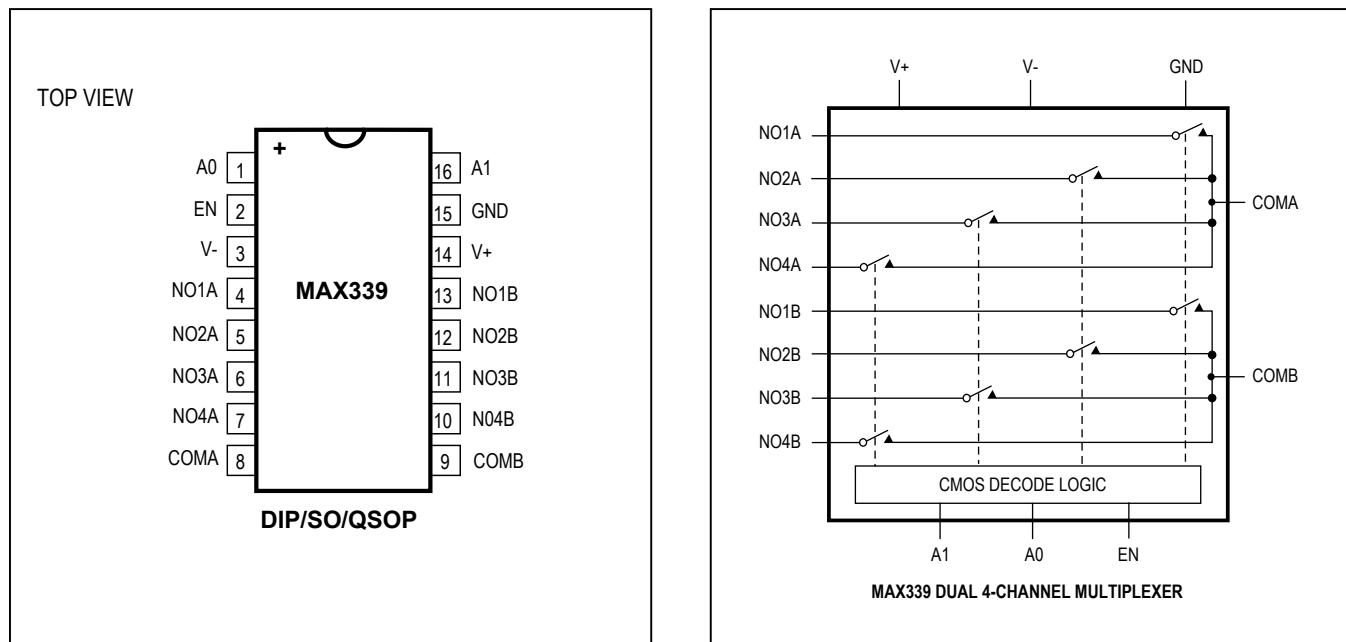


Figure 8. NO/COM Capacitance

## MAX338/MAX339

8-Channel/Dual 4-Channel,  
Low-Leakage, CMOS Analog Multiplexers

### Pin Configurations/Functional Diagrams/Truth Tables (continued)



A2	A1	A0	EN	ON SWITCH
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

**MAX338**

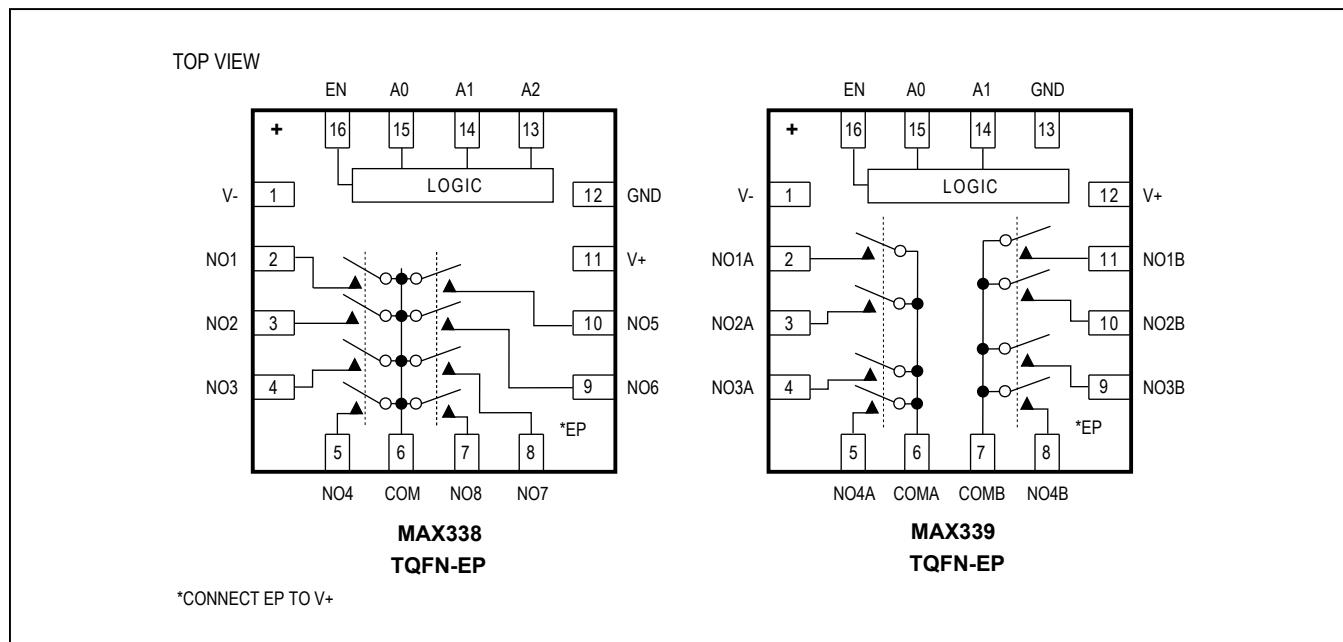
LOGIC "0"  $V_{AL} \geq 0.8V$ , LOGIC "1"  $V_{AH} \geq 2.4V$

A1	A0	EN	ON SWITCH
X	X	0	None
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

**MAX339**

LOGIC "0"  $V_{AL} \geq 0.8V$ , LOGIC "1"  $V_{AH} \geq 2.4V$

## Pin Configurations/Functional Diagrams/Truth Tables (continued)



## Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE
MAX338EPE+	-40°C to +85°C	16 PDIP
MAX338ESE+	-40°C to +85°C	16 Narrow SO
MAX338EJE	-40°C to +85°C	16 CERDIP
MAX338MJE	-55°C to +125°C	16 CERDIP***
MAX338MSE/PR3+	-55°C to +125°C	16 Narrow SO
<b>MAX339CEE+</b>	0°C to +70°C	16 QSOP
MAX339CPE+	0°C to +70°C	16 PDIP
MAX339CSE+	0°C to +70°C	16 Narrow SO
MAX339C/D	0°C to +70°C	Dice*

PART	TEMP RANGE	PIN-PACKAGE
MAX339EEE+	-40°C to +85°C	16 QSOP
MAX339ETE+	-40°C to +85°C	16 TQFN-EP** (5mm x 5mm)
MAX339EPE+	-40°C to +85°C	16 PDIP
MAX339ESE+	-40°C to +85°C	16 Narrow SO
MAX339EJE	-40°C to +85°C	16 CERDIP
MAX339MJE	-55°C to +125°C	16 CERDIP***
MAX339MSE/PR3+	-55°C to +125°C	16 Narrow SO

\*Contact factory for dice specifications.

\*\*EP = Exposed Pad

\*\*\*Contact factory for availability.

+Denotes a lead(Pb)-free/RoHS-compliant package.

## Package Information

For the latest package outline information and land patterns (footprints), go to [www.maximintegrated.com/packages](http://www.maximintegrated.com/packages). Note that a “+”, “#”, or “-” in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
16 PDIP	P16+1	<a href="#">21-0043</a>	—
16 Narrow SO	S16+1	<a href="#">21-0041</a>	<a href="#">90-0097</a>
16 QSOP	E16+5	<a href="#">21-0055</a>	<a href="#">90-0167</a>
16 TQFN-EP	T1655+3	<a href="#">21-0140</a>	<a href="#">90-0073</a>
16 CDIP	J16+4	<a href="#">21-0045</a>	—

## Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
4	4/12	Added the MAX338CEE+ / MAX338EEE+/ MAX338MSE /PR3 / MAX339CEE+ / MAX339EEE+ part and packaging information	1, 2, 6, 10, 11
5	10/17	Updated <i>Ordering Information</i> table	11
6	5/19	Updated <i>Electrical Characteristics</i> table	3, 4

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